

# Silicon Carbide Schottky Barrier Diode

| VRRM                 | 650 V | I <sub>F</sub> | 6 A     |
|----------------------|-------|----------------|---------|
| V <sub>F(Typ.)</sub> | 1.5 V | Qc             | 11.3 nC |

#### **Features**

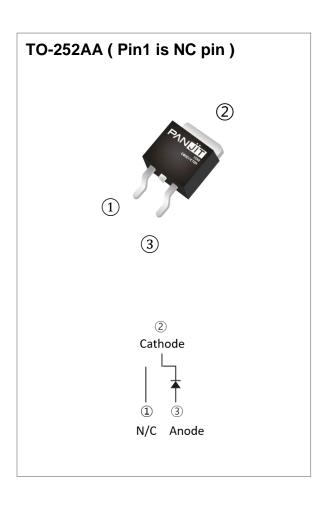
- Temperature Independent Switching Behavior
- High Surge Current Capability
- Positive Temperature Coefficient on V<sub>F</sub>
- Low Conduction Loss
- Zero Reverse Recovery
- High junction temperature 175 °C
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### **Mechanical Data**

- Case: TO-252AA molded plastic
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0113 ounces, 0.3217 grams

### **Application**

• PFC, UPS, PV Inverter, EV Charging Station, Welder



# Maximum Ratings and Thermal Characteristics (Tc = 25 °C unless otherwise specified)

| PARAMET                                                 | ≣R                                                 | SYMBOL           | LIMIT   | UNITS |  |
|---------------------------------------------------------|----------------------------------------------------|------------------|---------|-------|--|
| Repetitive Peak Reverse Voltage                         |                                                    | V <sub>RRM</sub> | 650     | V     |  |
| DC Blocking Voltage                                     |                                                    | V <sub>DC</sub>  | 650     | V     |  |
| Continuous forward current                              | T <sub>C</sub> = 150 °C                            | l <sub>F</sub>   | 6       | А     |  |
| Repetitive Peak Surge Current                           | T <sub>C</sub> = 25 °C , t <sub>p</sub> =10ms      |                  | 24      | Α     |  |
| Half Sine Wave, D=0.1                                   | T <sub>C</sub> =125 °C , t <sub>p</sub> =10ms      | IFRM             | 20      |       |  |
| Peak Forward Surge Current                              | $T_C= 25  ^{\circ}\text{C}$ , $t_p = 10 \text{ms}$ |                  | 28      |       |  |
| Half Sine Wave                                          | $T_C=125^{\circ}C$ , $t_p=10$ ms                   |                  | 24      | Α     |  |
| Peak Forward Surge Current  t <sub>D</sub> =10us, Pulse | Ifsm                                               | 320              | А       |       |  |
| Maximum Power Dissipation                               | P <sub>total</sub>                                 | 64.9             | W       |       |  |
| Operating Junction Temperature Range                    |                                                    | TJ               | -55~175 | °C    |  |
| Storage Temperature Range                               | T <sub>STG</sub>                                   | -55~175          | °C      |       |  |

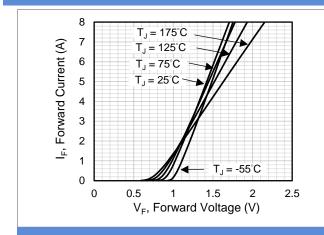


# **Electrical Characteristics** (T<sub>C</sub> = 25 °C unless otherwise specified)

| PARAMETER                 | SYMBOL         | TEST CONDITION                                  | MIN. | TYP. | MAX. | UNITS |  |
|---------------------------|----------------|-------------------------------------------------|------|------|------|-------|--|
|                           | VF             | I <sub>F</sub> = 6 A, T <sub>J</sub> = 25 °C    | -    | 1.5  | 1.7  | V     |  |
| Forward voltage drop      |                | I <sub>F</sub> = 6 A, T <sub>J</sub> = 175 °C   | -    | 1.8  | -    |       |  |
| Reverse leakage current   | I <sub>R</sub> | V <sub>R</sub> = 650 V, T <sub>J</sub> = 25 °C  | -    | 2    | 50   | μA    |  |
|                           |                | V <sub>R</sub> = 650 V, T <sub>J</sub> = 175 °C | -    | 0.03 | 1    | mA    |  |
| Total Capacitive Charge   | Qc             | I <sub>F</sub> = 6 A, V <sub>R</sub> = 400V     | -    | 11.3 | -    | nC    |  |
| Total Capacitance         | С              | $V_R = 1V, f = 1MHz$                            | -    | 228  | -    | pF    |  |
|                           |                | V <sub>R</sub> = 200V, f = 1MHz                 | -    | 18.9 | 1    | pF    |  |
|                           |                | V <sub>R</sub> = 400V, f = 1MHz                 | -    | 13.3 | -    | pF    |  |
| Capacitance Stored Energy | Ec             | V <sub>R</sub> = 400V                           | -    | 1.59 | 1    | μJ    |  |
| Thermal Resistance        | Rелс           |                                                 | -    | 2.31 | -    | °C/W  |  |



### **TYPICAL CHARACTERISTIC CURVES**



**Fig.1 Forward Characteristics** 

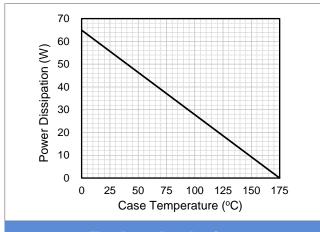


Fig.3 Power Derating Curve

300

250

200

150

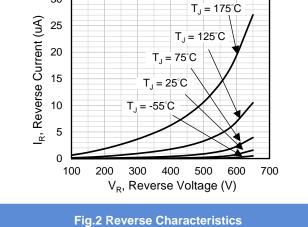
100

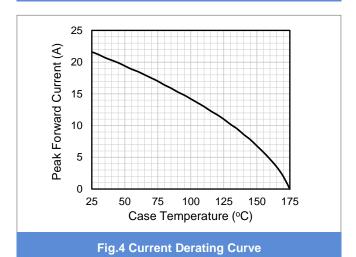
50

0

0.1

C<sub>J</sub>, Junction Capacitance (pF)





1000

**Fig.5 Typical Junction Capacitance** 

10

V<sub>R</sub>, Reverse Bias Voltage (V)

100

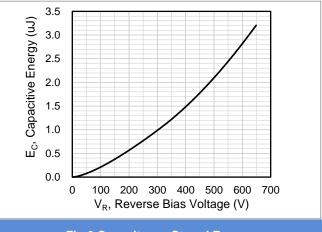


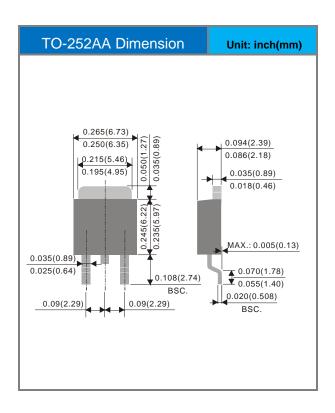
Fig.6 Capacitance Stored Energy

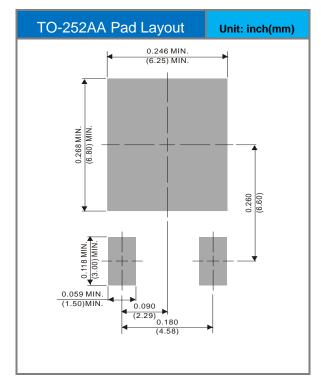


# **Product and Packing Information**

| Part No.   | Package Type | Packing Type         | Marking |  |
|------------|--------------|----------------------|---------|--|
| PCDC0665G1 | TO-252AA     | 3,000 pcs / 13" reel | CDC0665 |  |

## **Packaging Information & Mounting Pad Layout**







### Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are
  responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no
  representation or warranty that such applications will be suitable for the specified use without further testing
  or modification.
- The products shown herein are not designed and authorized for equipments requiring high level of reliability or relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, transportation equipment, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.